

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	43.4941	N/A	12.8935
RT2	44.0172	N/A	25.6570
RT3	8.1497	N/A	23.0010
RT4	54.3390	N/A	3.4485
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	9.0229 m	N/A	8.4691 m
CT2	40.6188 m	N/A	47.2116 m
CT3	2.6348 m	N/A	14.4179 m
CT4	2.1710	N/A	1.4298 m

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ($^{\circ}\text{C}/\text{W}$)			
Junction to	Ambient	Case	Foot
RF1	11.1778	N/A	3.1235
RF2	38.9903	N/A	2.2744
RF3	45.0243	N/A	29.7776
RF4	54.8076	N/A	29.8245
Thermal Capacitance (Joules/ $^{\circ}\text{C}$)			
Junction to	Ambient	Case	Foot
CF1	1.8281 m	N/A	973.4866 u
CF2	4.0865 m	N/A	1.1210 m
CF3	17.6257 m	N/A	2.2964 m
CF4	2.0237	N/A	22.9093 m

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

